800-2600nm 0.5mm InGaAs PIN Photodiode Version: 3.1 17-06-01

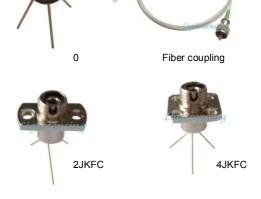
Model: LSIPD26-0.5

Features:

- Low noise, High reliability
- 800-2600nm wide wavelength range
- Active diameter 0.5mm
- Hermetic package TO46 Can or with receptacle or with fiber coupling

Applications:

- Gas Analyzer
- **Environment measurement**
- Optical sensor, Temperature sensing
- Covert IR sensing, Spectrography
- Medical and Chemical analysis
- Optical power meter, Space light detect equipment



Absolute maximum ratings:

parameter	symbol	value	unit
Operating temperature	Тор	-40~+85	$^{\circ}$ C
Storage temperature	Tstg	<i>-</i> 50∼+125	$^{\circ}$
Forward current	I _f	8	mA
Reverse voltage	VR	0.4	V
Soldering temperature(time)	Ts (10s)	260	$^{\circ}$

Electrical and optical characteristics:(T=25°C)

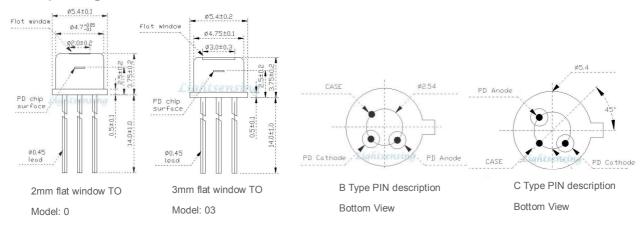
•	Electrical and optical characteristics.(1 200)				
parameter	symbol	unit	Value (typ.)		
Active diameter	Ф	mm	0.5		
Spectral range	λ	nm	800-2600		
Responsivity	Re (VR=0.2V,λ=850nm)	mA/mW	0.21		
	Re (VR=0.2V,λ=1310nm)	mA/mW	0.45		
	Re(VR=0.2V,λ=2300nm)	mA/mW	1.3		
	Re(VR=0.2V,λ=2600nm)	mA/mW	0.23		
Response time	Tr (RL=50Ω, VR=0.2V)	ns	13		
Dark current	ID(VR=0V)	nA	60		
	ID(VR=0.2V)	nA	400		
Reverse Breakdown voltage	VBR (IR=10uA)	V	1.5		
Junction capacitance	Cj (f=1MHz, VR=0V)	pF	100		
	Cj (f=1MHz, VR=0.2V)	pF	90		
Saturated Optical Power	Ps(VR =0.2V)	mW	6		
Operating voltage	VR	V	0-0.2		
Shunt impedance	Rsh (VR=10mV)	ΚΩ	70		
package	Hermetic package TO46 Can or with receptacle or fiber coupling				

NOTICE: The above product specifications are subject to change without notice.

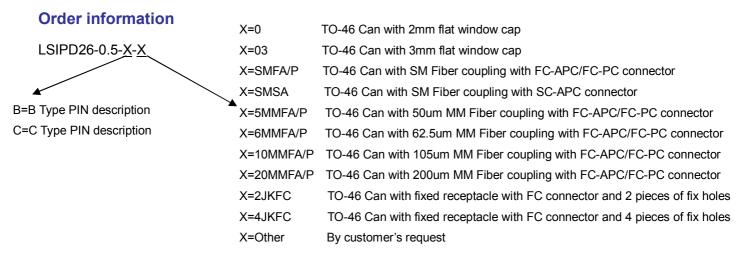
The typical Sensitivity curve



TO package and Lead



Note: In order to get other dimensions, please contact us.



The cautions